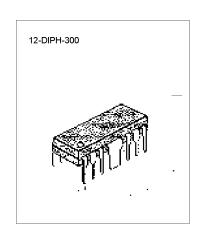


The KA2206B is a monolithic intergrated circuit consisting of a 2-channel power amplifier. It is suitable for stereo and bridge amplifier application of radio cassette tape recorders.

FEATURES

- High output power $\begin{aligned} \text{Stero} : P_0 &= 2.3 W(\text{Typ}) \text{ at } V_{\text{CC}} = 9 V, \, R_L = 4 \Omega \, . \\ \text{Bridge} : P_0 &= 4.7 W \text{ (Typ) at } V_{\text{CC}} = 9 V, \, R_L = 8 \Omega \, . \end{aligned}$
- Low switching distortion at high frequency.
- Small shock noise at the time of power on/off due to a built-in muting circuit
- Good ripple rejection due to a built-in ripple filter.
- Good channel separation.
- Soft tone at the time of output saturation.
- Closed loop voltage gain fixed 45dB (Bridge: 51dB) but availability with external resistor added.
- Minimum number of external parts required.
- Easy to design radiator fin.



ORDERING INFORMATION

Device	Package	Operating Temperature		
KS2206B	12-DIPH-300	-20℃ ~ +70℃		
KS22069BN	16-DIP-300A	-200 1700		

BLOCK DIAGRAM

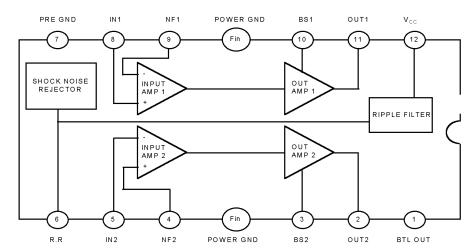


Fig. 1

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ABSOLUTE MAXIMUM RATINGS (Ta = 25 $^{\circ}$ C)

Characteristics	Symbol	Value	Unit	
Supply Voltage	V _{cc}	15	V	
Power Dissipation	P _D	4*	w	
Operating Temperature	T _{OPR}	-20 ~ +70	${\mathbb C}$	
Storage Temperature	T _{STG}	-40 ~ +150	${\mathbb C}$	

^{*} Fin is soldering on the PCB

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Test Condition		Min	Тур	Max	Unit
Operating Supply Voltage	Vcc				9	11	٧
Quiescent Circuit Current	Icca	V _I = 0, Stereo			40	55	mA
Closed Loop Voltage Gain	GVC	Stereo	V _I = -45dBm	43	45	47	dB
		Bridge]	49	51	53	dB
Channel Balance	СВ	Stereo		-1	0	+1	dB
		Stereo	$R_L=4\Omega$, THD = 10%,	1.7	2.3		w
Ouptut Power	Po		$R_L=8\Omega$, THD = 10%,		1.3		W
		Bridge	$R_L=8\Omega$, THD = 10%,		4.7		W
Total Harmonic Distortion	THD	Stereo	R_0 =250mW, R_L = 4Ω		0.3	1.5	%
		Bridge	1		0.5		%
Input Resistance	Rı			21	30		ΚΩ
Ripple Rejection Ratio	RR	Stereo,R _G =0Ω, V _r =150mW		40	46		dB
		f=100Hz					
Ouput Noise Voltage	V _{NO}	Stereo,R _G =0Ω			0.3	1.0	mW
		Stereo,R _G =10KΩ			0.5	2.0	mV
Cross Talk	СТ	Stereo,R _G =10KΩ, V _O =0dBm		40	55		dB

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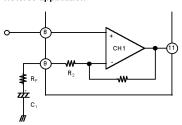
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Page: 2 (KA2206BN)



APPLICATION INFORMATION

1.Stereo application



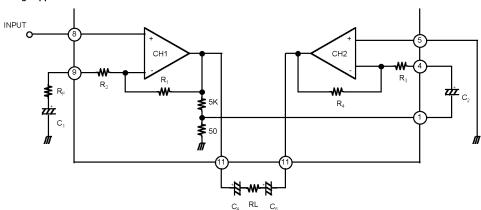
i) Fixed voltage gain (Pin 9 connected to GND directly)

$$G_V = 20 \log \frac{R_1}{R_2} (dB)$$

ii) Variable voltage gain (Rf and C₁ connected with pin 9)

$$G_V = 20 \log \frac{R_1}{R_2 + R_F}$$
 (dB)

2. Bridge application



i) Fixed voltage gain (Pin 9 connected to GND directly)

$$G_V = 20 \log \frac{R_1}{R_2} + 6(dB)$$

ii) Variable voltage gain $R_{\text{\tiny F}}$ and $C_{\text{\tiny 1}}$ connected with pin 9)

$$G_V = 20 \log \frac{R_1}{R_2 + R_F} + 6(dB)$$

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APPLICATION CIRCUIT

1. Stereo Amplifier

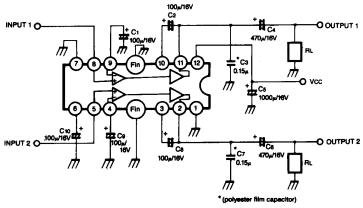


Fig. 2

2. Bridge Amplifier

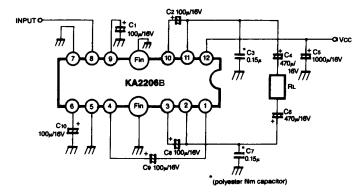


Fig. 3



